

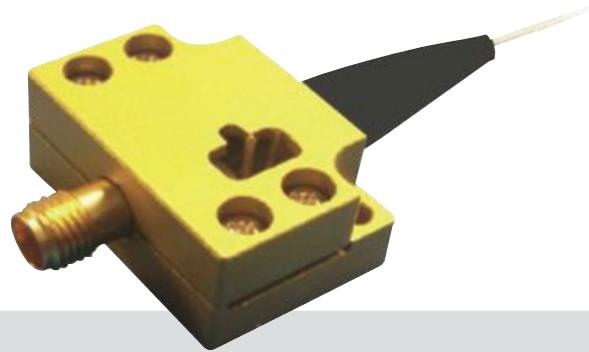
# F-PD-30-D-K

## 30 GHz Linear InGaAs PIN Photodetector



The F-PD-30-D-K is a highly linear, 30 GHz bandwidth InGaAs PIN photodetector that is ideal for use in O/E front-ends requiring wide band frequency response. The coplanar waveguide photodiode design optimizes speed and sensitivity for the 1260 nm through 1610 nm wavelength range, and assures a 30 GHz frequency response necessary for digital and analog applications. The front-illuminated mesa-structured PIN design allows a high input power level of up to 20 mW. The

F-PD-30-D-K is available in a standard 2-pin package with SMA RF connector output for ease of assembly.



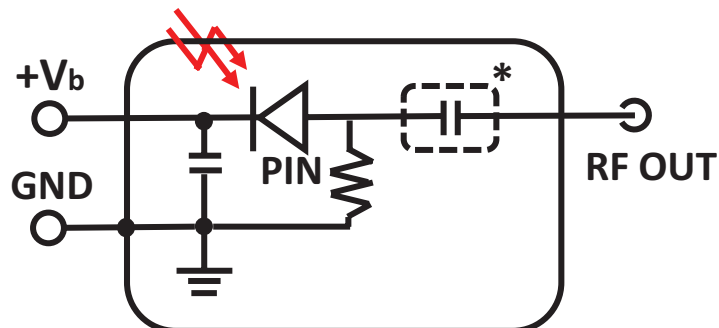
### Features

- Bandwidth 60 KHz to 30 GHz, AC coupled
- DC to 30 GHz, DC coupled
- Highly linear to 30 mW+ input power
- Operating Temperature from -10 °C to +60 °C (TQ Version: -45 °C to +75 °C)
- High current handling up to 35 mA
- Flat frequency response,  $\pm 1$  dB
- Useful spectral range 850 nm – 165 nm

### Use in:

- 30 GHz Analog RF over Fiber
- Optically amplified photonics link
- RZ and NRZ up to 20 Gb/s
- Coherent lightwave systems
- Front-End O/E converter for test instrument

### Functional Diagram



## Specifications

Optimized Operating Wavelength	1260 nm to 1610 nm
Useful Operating Wavelength	850 nm to 1650 nm
Optical Input Level	10 mW average, 20 mW peak
S21 3 dB Bandwidth	28 GHz min., 30 GHz typ.
S22 Characteristics	< -10 dB @ 20 GHz
Low Frequency Cut Off	60 kHz
Responsivity	0.80 A/W @ 1550 nm typ.
Dark Current @ 25°C	10 nA typ., 100 nA max.
Optical Return Loss	-30.00 dB typ.
Optical PDL @ 1550 nm	0.05 dB max.
Bias Voltage	4 V typ.
Impedance	50 $\Omega$
Coupling	DC-Coupled

## General

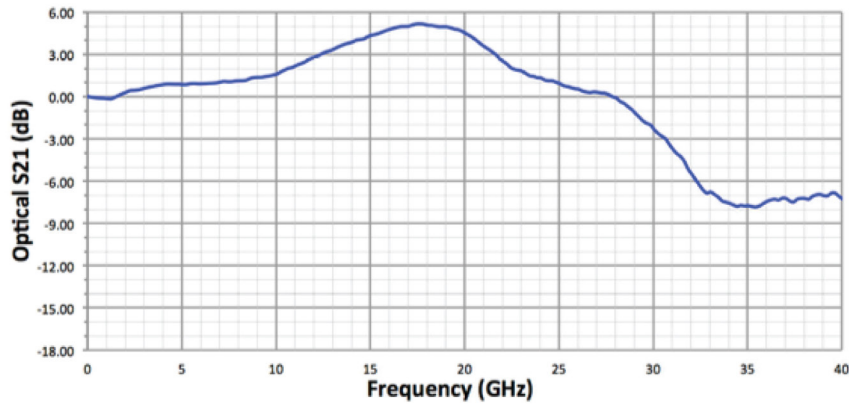
## Mechanical

Operating Temperature	-10 °C to +60 °C
Storage Temperature	-55 °C to +75 °C
Operating Humidity	85%
Photodiode Bias Voltage	5 V, $\pm$ 1 V DC
Package Type	K Connector Female
Dimensions	30 mm x 20 mm x 14 mm
Fiber Connector	FC/APC
Optical Fiber	SMF-28 with 900 mm tube (HI1060 fiber available upon request)

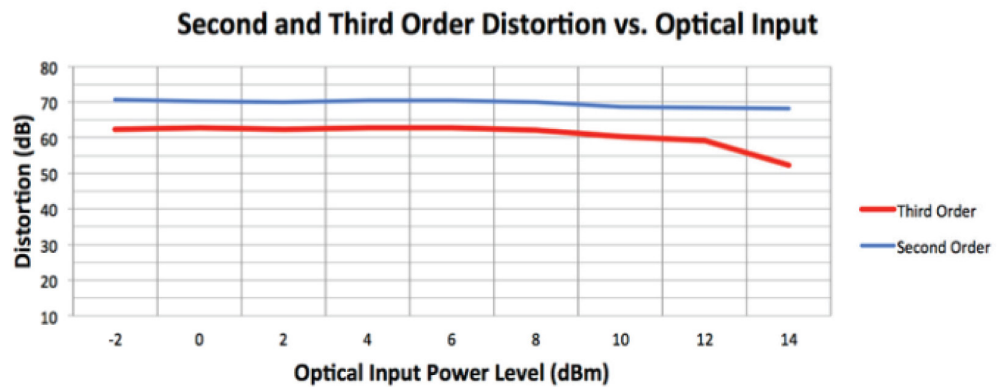
## Absolute Maximum Ratings

PIN Bias Voltage	+2.0 to +7 V
Forward Current	35 mA
Optical Input Power	30 mW
Lead Soldering Temp (10s)	250 °C

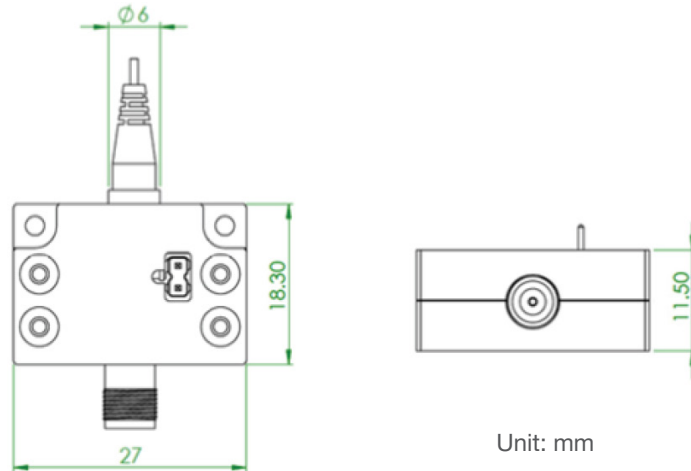
## S21 O/E Response



## CSO, CTB Linearity Measurement



## Mechanical Drawing



## Related Amplifier

- F-AMP-SM



The F-AMP-SM is a high-gain 1064 nm pre-amplifier module in a compact housing